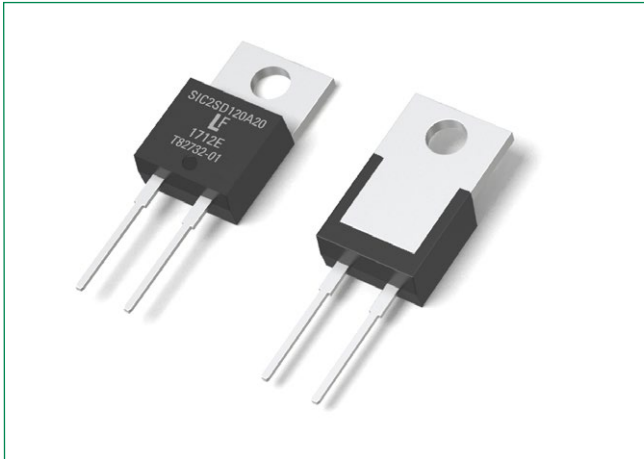


LSIC2SD120A20



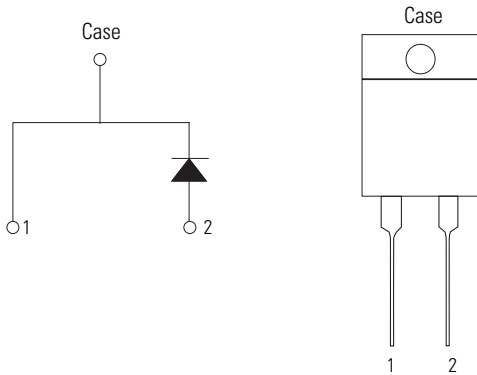
Description

This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-220-2L



Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS conform
- Littelfuse "HF" logo = **HF** Halogen Free
- Littelfuse "PB-free" logo = Pb-free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit
Repetitive Peak Reverse Voltage	V_{RRM}	-	1200	V
DC Blocking Voltage	V_R	$T_J = 25\text{ °C}$	1200	V
Continuous Forward Current	I_F	$T_C = 25\text{ °C}$	54.5	A
		$T_C = 135\text{ °C}$	26.0	
		$T_C = 150\text{ °C}$	20.0	
Non-Repetitive Forward Surge Current	I_{FSM}	$T_C = 25\text{ °C}, T_p = 10\text{ ms}, \text{Half sine pulse}$	140	A
Power Dissipation	P_{Tot}	$T_C = 25\text{ °C}$	250	W
		$T_C = 110\text{ °C}$	108	
Operating Junction Temperature	T_J	-	-55 to 175	°C
Storage Temperature	T_{STG}	-	-55 to 150	°C
Soldering Temperature	T_{sold}	-	260	°C

Electrical Characteristics

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Forward Voltage	V_F	$I_F = 20\text{ A}, T_J = 25\text{ }^\circ\text{C}$	-	1.5	1.8	V
		$I_F = 20\text{ A}, T_J = 175\text{ }^\circ\text{C}$	-	2.2	-	
Reverse Current	I_R	$V_R = 1200\text{ V}, T_J = 25\text{ }^\circ\text{C}$	-	<1	100	μA
		$V_R = 1200\text{ V}, T_J = 175\text{ }^\circ\text{C}$	-	15	-	
Total Capacitance	C	$V_R = 1\text{ V}, f = 1\text{ MHz}$	-	1142	-	pF
		$V_R = 400\text{ V}, f = 1\text{ MHz}$	-	108	-	
		$V_R = 800\text{ V}, f = 1\text{ MHz}$	-	82	-	
Total Capacitive Charge	Q_C	$V_R = 800\text{ V}, Q_C = \int_0^{V_R} C(V)dV$	-	115	-	nC

Footnote: $T_J = +25\text{ }^\circ\text{C}$ unless otherwise specified

Thermal Characteristics

Characteristics	Symbol	Conditions	Value			Unit
			Min.	Typ.	Max.	
Thermal Resistance	$R_{\theta JC}$	-	-	0.6	-	$^\circ\text{C/W}$

Figure 1: Typical Forward Characteristics

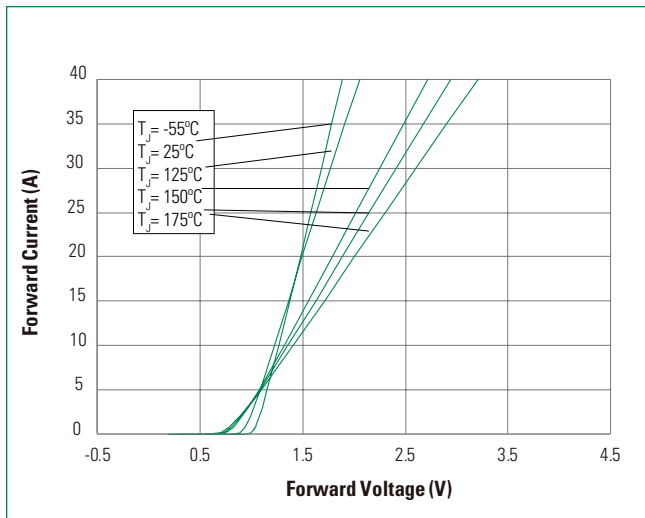


Figure 2: Typical Reverse Characteristics

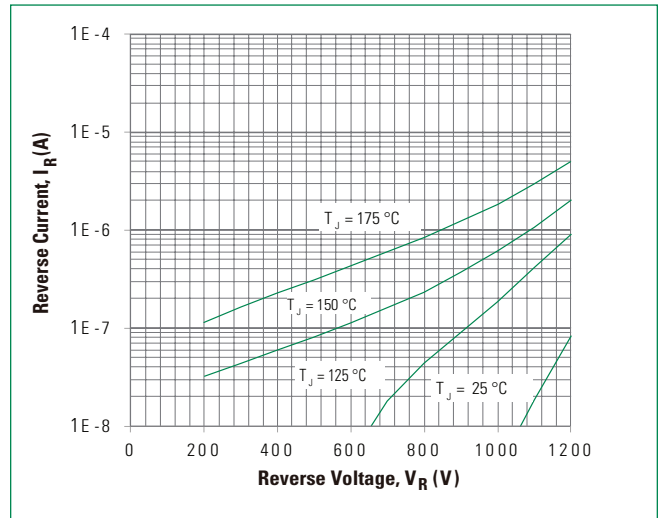


Figure 3: Power Derating

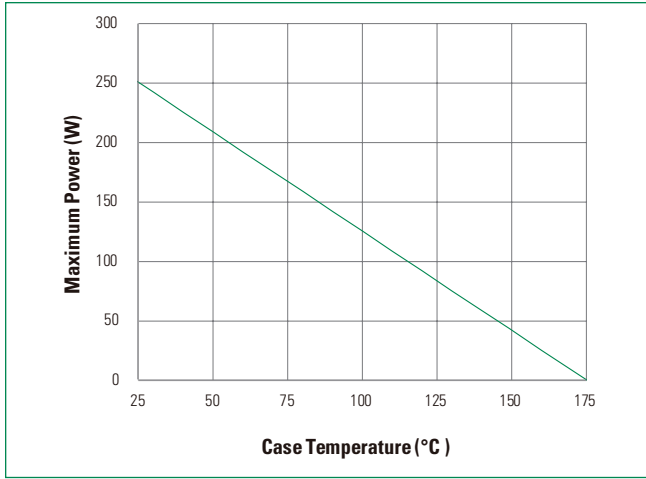


Figure 4: Current Derating

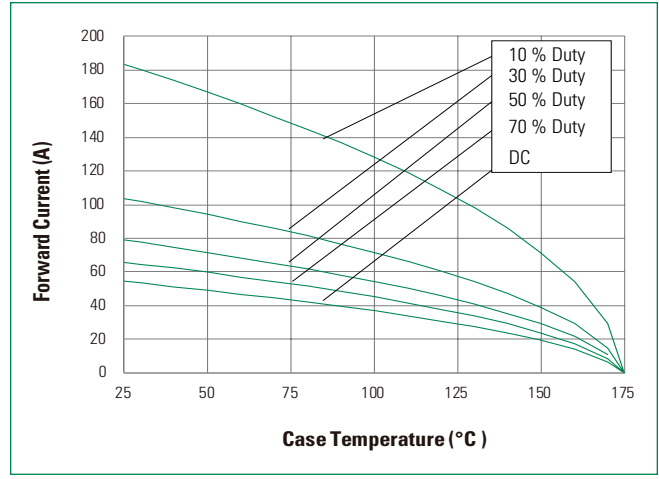


Figure 5: Capacitance vs. Reverse Voltage

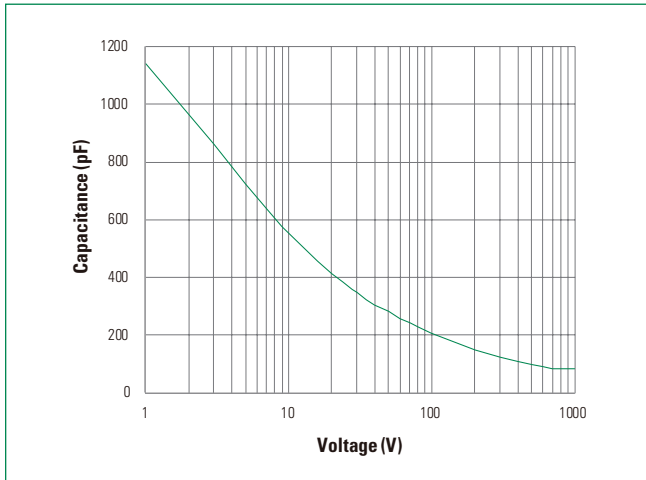


Figure 6: Capacitive Charge vs. Reverse Voltage

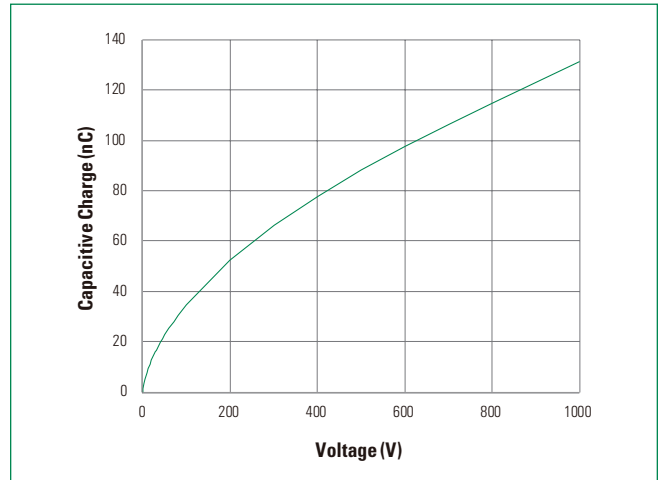


Figure 7: Stored Energy vs. Reverse Voltage

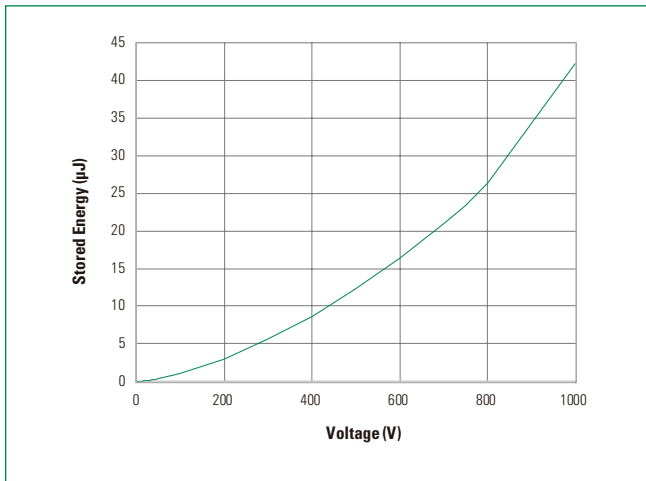
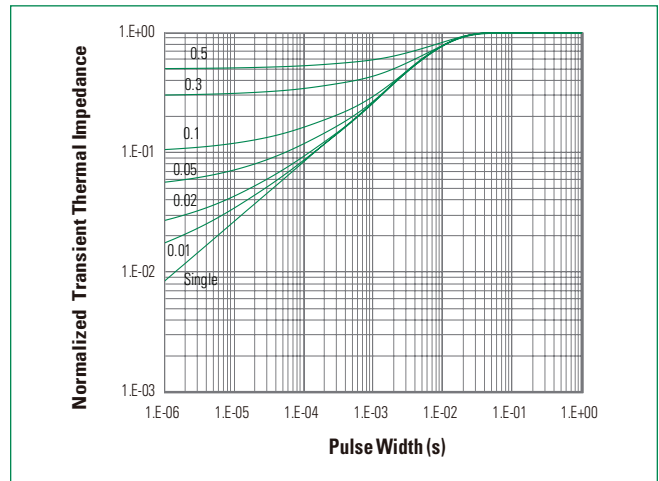
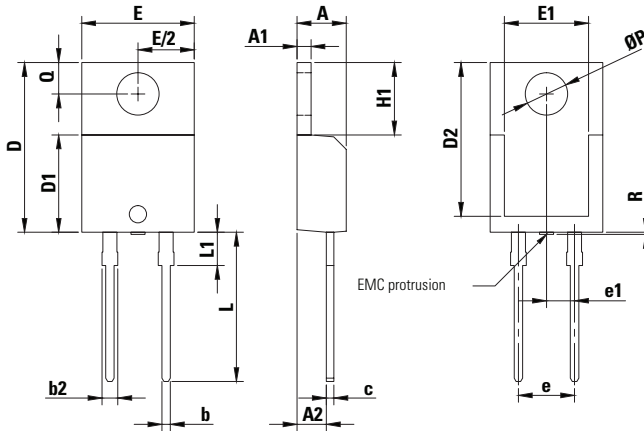


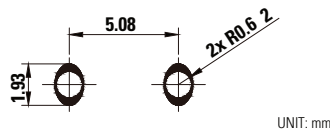
Figure 8: Transient Thermal Impedance



Dimensions-Package TO-220-2L

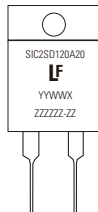


Recommended Solder Pad Layout



Symbol	Millimeters		
	Min	Norm	Max
A	4.32	4.45	4.70
A1	1.14	1.27	1.40
A2	2.20	-	2.74
b	0.69	-	0.90
b2	1.17	-	1.62
c	0.36	-	0.60
D	14.90	-	15.90
D1	8.62	-	9.40
D2	12.50	-	12.95
E	9.70	10.18	10.36
E1	7.57	7.61	8.30
e1	-	2.54	-
e	5.03	5.08	5.13
H1	6.30	6.55	6.80
L	12.88	13.50	14.00
L1	2.39	-	3.25
øP	3.50	3.84	3.96
Q	2.65	-	3.05
R	-	-	0.25

Part Numbering and Marking System



- SIC = SiC Diode
- 2 = Gen2
- SD = Schottky Diode
- 120 = Voltage Rating (1200 V)
- A = TO-220 Package (2 Lead)
- 20 = Current Rating (20 A)
- YY = Year
- WW = Week
- X = Trace Code (any letter)
- ZZZZZ-ZZ = Lot Number

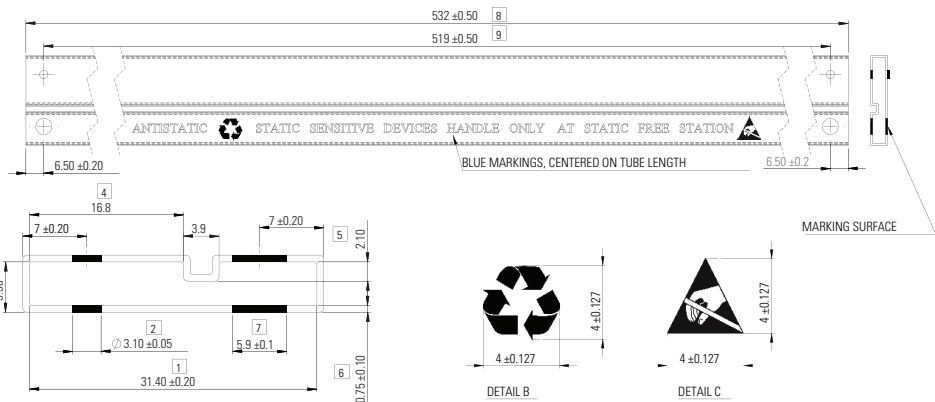
Packing Options

Part Number	Marking	Packing Mode	M.O.Q
LSIC2SD120A20	SIC2SD120A20	Tube (50pcs)	1000

Packing Specification (Tube for TO-220-2L)

NOTES:

1. Material transparent extruded PVC with antistatic dipping
2. Radius : 0.5 maximum unless otherwise specified
3. Critical areas : Labelled in Box
4. All pin plug holes are considered critical dimension
5. Marking Font Type : Times new roman, 3.12±0.127 in height
6. Material Thickness : 0.75±0.10
7. Tolerance unless otherwise specified: Decimal: ±0.05 Angle: ±1°
8. Unit : Millimeter (mm)



Disclaimer Notice - Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.